



IXDP35N60B Information

www.heiseper.com

Part Number IXDP35N60B

Manufacturer IXYS

Category Discrete Semiconductor Products

Transistors - IGBTs - Single

Description IGBT 600V 60A 250W TO220AB

Package TO-220-3

For the pricing/inventory/lead time, please contact

Website: https://www.heisener.com For Reference Only

E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









IXDP35N60B Specifications

Manufacturer Part Number	IXDP35N60B
Manufacturer	IXYS
Category	Discrete Semiconductor Products
	Transistors - IGBTs - Single
Package	TO-220-3
Series	-
IGBT Type	NPT
Voltage - Collector Emitter Breakdown (Max)	600V
Current - Collector (Ic) (Max)	60A
Current - Collector Pulsed (Icm)	70A
Vce(on) (Max) @ Vge, Ic	2.7V @ 15V, 35A
Power - Max	250W
Switching Energy	1.6mJ (on), 800µJ (off)
Input Type	Standard
Gate Charge	120nC
Td (on/off) @ 25°C	-
Test Condition	300V, 35A, 10 Ohm, 15V
Reverse Recovery Time (trr)	-
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Package / Case	TO-220-3
Supplier Device Package	TO-220AB
	Report errors?

IXDP35N60B Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

IXDP35N60B Payment Methods





















IXDP35N60B Shipping Methods













If you have any question about IXDP35N60B, please do not hesitate to contact us!

Website: https://www.heisener.com E-mail: salesdept@heisener.com